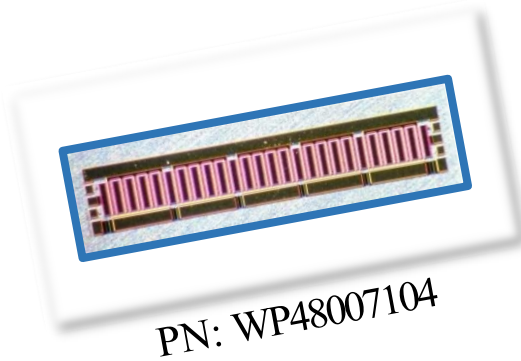




WP48007104

104W, 48V GaN HEMT Die



The WP48007104 is a 104W gallium nitride (GaN) High Electron Mobility Transistor (HEMT). This GaN HEMT is a wideband transistor optimized for 5.8GHz operation in a user-friendly device for high bandwidth applications. Gallium nitride (GaN) HEMT is a device optimized for 5G. GaN HEMT resistance is only 1/10 that of silicon transistors, making it capable of switching frequencies faster for greater energy efficiency.

Features

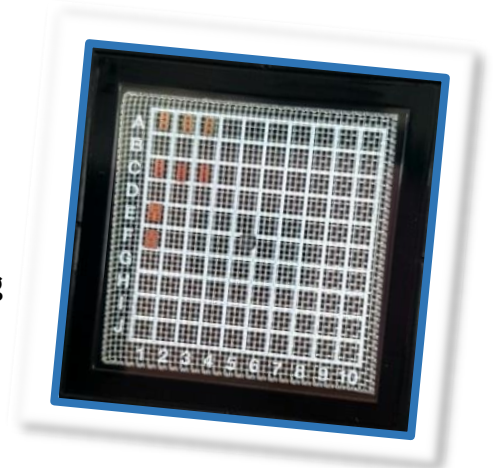
- Up to 8 GHz Operation
- 14.0 dB Typical Small Signal Gain @ 3.5 GHz
- 104 W Typical Psat @5.8GHz
- 48V Operation
- High Breakdown Voltage
- High Breakdown Voltage
- High Efficiency
- Reliability Monitoring Supporting

Applications

- U/VHF Amplifiers
- Broadband Amplifiers
- Base Station Communications
- Drone, UAV
- WiMAX, LTE, WCDMA, GSM
- WPT, V2X
- Radar application

Packaging Information

- Bare die are shipped in Wafer-level with Expander Ring or Gel-Pak® containers.
- Possible UV Curing for Wafer-level with dicing saw



Absolute Maximum Ratings (not simultaneous) at 25 °C

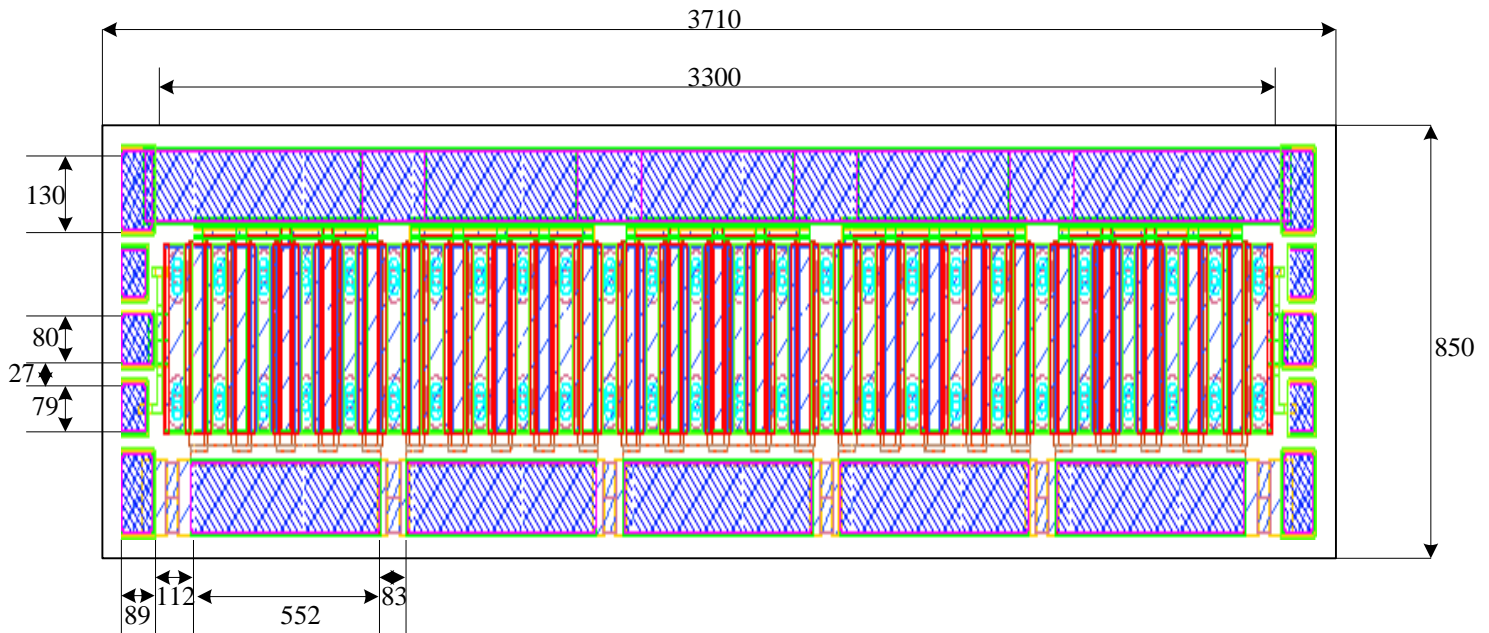
Parameter	Parameter	Typical Value	Units	Conditions
Threshold voltage @ Id=1mA/mm, Vd=10V	V _{to}	-3.4	V	25°C
Breakdown voltage @ Id=1mA/mm	V _{DG}	160	V	25°C
Drain-source current, Id @ Vd=10V, Vg=0	I _{dss}	800	mA/mm	25°C
Operating Junction Temperature	T _J	225	°C	
Storage Temperature	T _{STG}	-65, +150	°C	
Thermal Resistance, Junction to Case (packaged)	R _{θJC}		°C/W	
Thermal Resistance, Junction to Case (die only)	R _{θJC}		°C/W	
Mounting Temperature (30 seconds)	T _S	320	°C	30 seconds

Electrical Characteristics (Frequency = 3.5 GHz unless otherwise stated; TC = 25 °C)

Parameter	Parameter	Typical Value	Units	Conditions
DC Characteristics				
Ohmic contact resistance	RC	0.3	Ohm-mm	25°C
Maximum Drain-source current, Id @ Vd=10V, Vg=1V (1X125µm device)	I _{dmax}	1000	mA/mm	25°C
Max. trans-conductance, @ Vd=10V, Vg=-4V ~ -1V (1X125µm device)	GM_PEAK	290	mS/mm	25°C
Maximum Drain-source current, Id @ Vd=10V, Vg=1V (1X125µm device)	I _{dmax}	1000	mA/mm	25°C
RF Characteristics				
Small Signal Gain	G _{SS}	>12	dB	V _{DD} =48V, I _{DQ} =600mA
Saturated Power Output	P _{SAT}	104	W	V _{DD} =48V, I _{DQ} =600mA
Drain Efficiency	η	>60	%	V _{DD} =48V, I _{DQ} =600mA
Intermodulation Distortion	IM3	<-30	dBc	V _{DD} =48V, I _{DQ} =600mA
Output Mismatch Stress	VSWR	10:1	ψ	



DIE Dimensions (units in microns)



Overall die size 3710 x 850 (+0/-50) microns, die thickness 100 (+/- 10) microns.
All Gate and Drain pads must be wire bonded for electrical connection.

Assembly Notes:

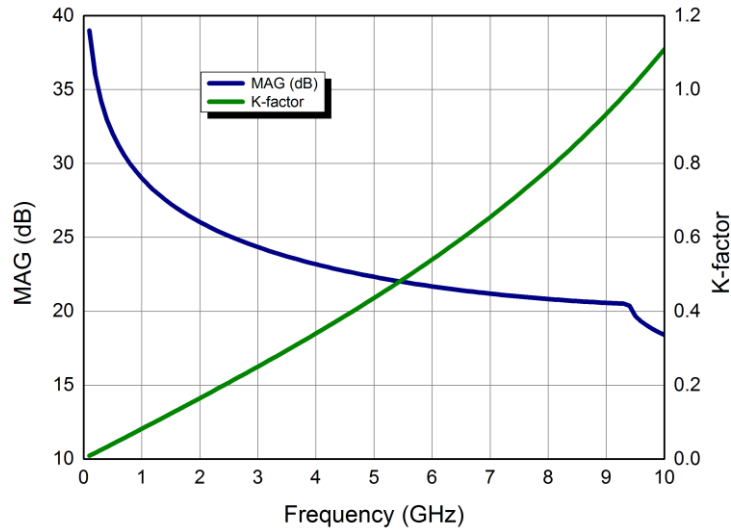
- Recommended solder is AuSn (80/20) solder. Refer to Wavepia's guide for the Eutectic Die Bond Procedure
- Vacuum collet is the preferred method of pick-up.
- The backside of the die is the Source (ground) contact.
- Die back side gold plating is 5 microns thick minimum.
- Thermosonic ball or wedge bonding are the preferred connection methods.
- Gold wire must be used for connections.



Typical Performance

Simulated Maximum Available Gain (MAG) and K Factor of the WP48007104

$V_{DD} = 48\text{ V}$, $I_{DQ} = 600\text{ mA}$

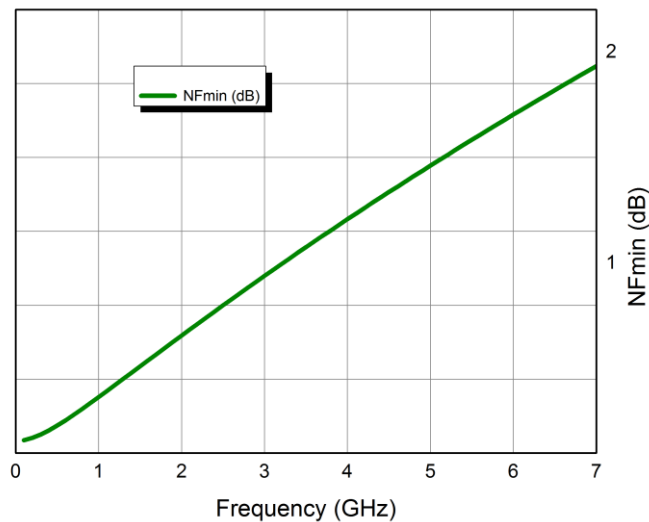


Intrinsic die parameters - reference planes at centers of gate and drain bonding pads. No wire bonds assumed.

Typical Performance

Simulated Minimum Noise Figure of the WP48007104

$V_{DD} = 48\text{ V}$, $I_{DQ} = 600\text{ mA}$





Typical Die S-Parameters

(Small Signal, $V_{DS} = 48\text{ V}$, $I_{DQ} = 600\text{ mA}$, magnitude / angle)

Frequency	Mag S11	Ang S11	Mag S21	Ang S21	Mag S12	Ang S12	Mag S22	Ang S22
100MHz	0.966451	-115.355	54.80452	120.2714	0.006897	30.42056	0.59824	-159.811
200MHz	0.957718	-144.844	30.74865	104.3057	0.007738	14.60403	0.661279	-167.802
300MHz	0.955657	-156.101	20.98563	97.35368	0.007921	7.801237	0.676724	-170.734
400MHz	0.954997	-161.911	15.85165	93.07822	0.007976	3.675007	0.683447	-172.013
500MHz	0.954808	-165.433	12.70458	89.9283	0.007988	0.674357	0.687738	-172.589
600MHz	0.954833	-167.789	10.58092	87.35637	0.007981	-1.74825	0.691259	-172.811
700MHz	0.954983	-169.472	9.051238	85.12231	0.007962	-3.83293	0.694585	-172.836
800MHz	0.955215	-170.731	7.89626	83.10495	0.007935	-5.70083	0.69795	-172.744
900MHz	0.95551	-171.708	6.99265	81.23691	0.007902	-7.41933	0.701454	-172.582
1000MHz	0.955856	-172.488	6.265802	79.47794	0.007863	-9.02866	0.70514	-172.377
1100MHz	0.956245	-173.123	5.667981	77.80267	0.007819	-10.5542	0.709022	-172.148
1200MHz	0.95667	-173.651	5.167242	76.19443	0.007771	-12.0126	0.713097	-171.907
1300MHz	0.957128	-174.097	4.741405	74.64187	0.00772	-13.4152	0.717357	-171.664
1400MHz	0.957615	-174.479	4.374595	73.13706	0.007665	-14.7699	0.721786	-171.423
1500MHz	0.958128	-174.81	4.055151	71.67433	0.007606	-16.0823	0.726365	-171.19
1600MHz	0.958662	-175.099	3.774318	70.24953	0.007545	-17.3567	0.731076	-170.968
1700MHz	0.959215	-175.355	3.525391	68.85956	0.007481	-18.5961	0.7359	-170.758
1800MHz	0.959785	-175.584	3.303151	67.50209	0.007414	-19.8028	0.740815	-170.563
1900MHz	0.960369	-175.79	3.103474	66.1753	0.007345	-20.9787	0.745803	-170.383
2000MHz	0.960965	-175.976	2.923057	64.87776	0.007274	-22.125	0.750845	-170.219
2100MHz	0.96157	-176.147	2.759223	63.6083	0.007201	-23.2431	0.755923	-170.071
2200MHz	0.962182	-176.303	2.609778	62.366	0.007127	-24.3338	0.761022	-169.939
2300MHz	0.962799	-176.448	2.472909	61.15002	0.007051	-25.398	0.766124	-169.823
2400MHz	0.963419	-176.583	2.347101	59.95969	0.006974	-26.4362	0.771217	-169.723
2500MHz	0.96404	-176.709	2.231078	58.79436	0.006896	-27.4492	0.776287	-169.637
2600MHz	0.964662	-176.827	2.123759	57.65349	0.006816	-28.4375	0.781322	-169.566
2700MHz	0.965282	-176.939	2.02422	56.53655	0.006737	-29.4015	0.786312	-169.509
2800MHz	0.965899	-177.045	1.931667	55.44303	0.006656	-30.3418	0.791247	-169.464
2900MHz	0.966511	-177.146	1.845413	54.37245	0.006575	-31.2589	0.79612	-169.432
3000MHz	0.967119	-177.243	1.76486	53.32436	0.006494	-32.1532	0.800922	-169.412
3100MHz	0.96772	-177.336	1.689485	52.29829	0.006413	-33.0251	0.805647	-169.403
3200MHz	0.968314	-177.425	1.618829	51.2938	0.006331	-33.875	0.810291	-169.404
3300MHz	0.9689	-177.511	1.552486	50.31043	0.00625	-34.7035	0.814849	-169.414
3400MHz	0.969477	-177.594	1.490097	49.34775	0.006168	-35.5109	0.819316	-169.433
3500MHz	0.970045	-177.674	1.431341	48.4053	0.006087	-36.2977	0.823691	-169.461
3600MHz	0.970604	-177.753	1.375932	47.48264	0.006006	-37.0643	0.827971	-169.496
3700MHz	0.971153	-177.829	1.323613	46.57934	0.005926	-37.8111	0.832155	-169.538
3800MHz	0.971691	-177.903	1.274153	45.69496	0.005846	-38.5386	0.83624	-169.586
3900MHz	0.972218	-177.976	1.227343	44.82905	0.005766	-39.2471	0.840227	-169.641



Typical Die S-Parameters

(Small Signal, $V_{DS} = 48\text{ V}$, $I_{DQ} = 600\text{ mA}$, magnitude / angle)

Frequency	Mag S11	Ang S11	Mag S21	Ang S21	Mag S12	Ang S12	Mag S22	Ang S22
4000MHz	0.972735	-178.047	1.182994	43.98119	0.005687	-39.9371	0.844115	-169.7
4100MHz	0.973241	-178.116	1.140936	43.15095	0.005608	-40.609	0.847905	-169.765
4200MHz	0.973735	-178.184	1.101011	42.33789	0.005531	-41.2633	0.851596	-169.834
4300MHz	0.974218	-178.251	1.063077	41.5416	0.005453	-41.9002	0.855191	-169.907
4400MHz	0.974691	-178.317	1.027004	40.76166	0.005377	-42.5203	0.858689	-169.983
4500MHz	0.975152	-178.381469	0.992673	39.99766	0.005301	-43.1238	0.862092	-170.063
4600MHz	0.975601	-178.445	0.959973	39.24919	0.005227	-43.7113	0.865401	-170.146
4700MHz	0.97604	-178.507598	0.928803	38.51585	0.005152	-44.2831	0.868618	-170.231
4800MHz	0.976468	-178.569255	0.899071	37.79724	0.005079	-44.8395	0.871745	-170.319
4900MHz	0.976885	-178.630041	0.87069	37.093	0.005007	-45.3809	0.874784	-170.409
5000MHz	0.977292	-178.69	0.843581	36.40273	0.004935	-45.9077	0.877736	-170.5
5100MHz	0.977688	-178.749173	0.817671	35.72606	0.004864	-46.4202	0.880603	-170.593
5200MHz	0.978074	-178.808	0.79289	35.06263	0.004794	-46.9188	0.883388	-170.687
5300MHz	0.978449	-178.8653	0.769175	34.4121	0.004725	-47.4038	0.886092	-170.783
5400MHz	0.978815	-178.922317	0.746467	33.7741	0.004657	-47.8756	0.888718	-170.879
5500MHz	0.979171	-178.979	0.724712	33.1483	0.00459	-48.3343	0.891267	-170.976
5600MHz	0.979517	-179.034398	0.703857	32.53438	0.004524	-48.7805	0.893742	-171.074
5700MHz	0.979854	-179.089512	0.683855	31.93201	0.004458	-49.2142	0.896145	-171.172
5800MHz	0.980182	-179.144037	0.664661	31.34087	0.004393	-49.636	0.898477	-171.27
6000MHz	0.980501	-179.197993	0.646234	30.76067	0.004329	-50.0459	0.900742	-171.369
6100MHz	0.980812	-179.2514	0.628533	30.19109	0.004266	-50.4443	0.90294	-171.468
6200MHz	0.981114	-179.304276	0.611522	29.63187	0.004204	-50.8315	0.905074	-171.567
6300MHz	0.981408	-179.356637	0.595167	29.0827	0.004143	-51.2077	0.907146	-171.666
6400MHz	0.981694	-179.408498	0.579435	28.54332	0.004083	-51.5732	0.909158	-171.765
6500MHz	0.981972	-179.459875	0.564296	28.01347	0.004023	-51.9281	0.911111	-171.863
6600MHz	0.982243	-179.510781	0.549722	27.49288	0.003964	-52.2728	0.913008	-171.961
6700MHz	0.982506	-179.56123	0.535684	26.9813	0.003906	-52.6074	0.91485	-172.059
6800MHz	0.982762	-179.611234	0.522158	26.4785	0.003849	-52.9322	0.916639	-172.157
6900MHz	0.983011	-179.660806	0.509121	25.98423	0.003792	-53.2473	0.918377	-172.254
7000MHz	0.983253	-179.709956	0.496549	25.49827	0.003737	-53.553	0.920064	-172.35
7100MHz	0.983489	-179.758696	0.48442	25.02039	0.003682	-53.8494	0.921704	-172.446
7200MHz	0.983719	-179.807037	0.472716	24.55038	0.003628	-54.1367	0.923297	-172.542
7300MHz	0.983942	-179.854987	0.461417	24.08803	0.003574	-54.4151	0.924845	-172.636
7400MHz	0.98416	-179.902558	0.450505	23.63313	0.003521	-54.6848	0.926349	-172.731
7500MHz	0.984371	-179.949759	0.439963	23.18549	0.003469	-54.9459	0.927812	-172.824
7600MHz	0.984577	-179.996597	0.429775	22.74492	0.003418	-55.1985	0.929233	-172.917
7700MHz	0.984778	179.956917	0.419925	22.31123	0.003367	-55.4429	0.930615	-173.009
7800MHz	0.984973	179.910776	0.4104	21.88425	0.003317	-55.6791	0.931958	-173.101
7900MHz	0.985163	179.864971	0.401186	21.4638	0.003268	-55.9073	0.933265	-173.192

Contact WAVEPIA to receive this s-parameter file in “.s2p” format at plptune@wavepia.com

Disclaimer

Information furnished by WAVEPIA Co., Ltd. is believed to be accurate and reliable. However, no responsibility is assumed by WAVEPIA Co., Ltd. for its use, nor for any infringements of patents or other rights of third parties that may result from its use. The information contained is provided “as it is” and with all defects, and the whole risk associated with such information is entirely with the user. Specifications subject to change without notice. WAVEPIA Co., Ltd. and registered trademarks are the property of their respective owners. Customers must search and verify the updated information before placing orders for our products. We makes no guarantee or representation regarding the information contained herein the using of products for any specific purpose. WAVEPIA Co., Ltd. products are not warranted or authorized for use as key components in conditions, or other applications where a failure would be expected to cause severe personal injury or death.

For more information, please contact :

- *For more details : WAVEPIA Co., Ltd.*
- *4-5, Sucheon-ro, Osan-si, Gyeonggi-do 18110, Republic of Korea*
- *Application Support: platune@wavepia.com*

Sanghun Lee
CTO
WAVEPIA, IC DESIGN
+82.31.8058.3374